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# Q-Class Power MOSFETs

Chopper Topologies in ISOPLUS i4-PAC<sup>™</sup>

## Preliminary data

MOSEET

Symbol

Conditions



Characteristic Values





### Features

- Q-Class Power MOSFET technology low  $R_{\mbox{\tiny DSon}}$ 
  - low gate charge for high frequency operation
  - unclamped inductive switching (UIS) capability
- dv/dt ruggedness
- HiPerDyn<sup>™</sup> FRED
  - consisting of series connected diodes
  - enhanced dynamic behaviour for high frequency operation
- ISOPLUS i4-PAC<sup>™</sup> package
  - isolated back surface
  - UL registered E72873
  - low coupling capacity
  - between pins and heatsink - enlarged creepage towards heatsink
  - application friendly pinout
  - low inductive current path
- high reliability
- industry standard outline

#### Applications

- chopper for power factor correction
- supply of high frequency transformer - switched mode power supplies
  - welding converters

Symbol Conditions		Maximum Ratings		
V <sub>DSS</sub>	$T_{vJ} = 25^{\circ}C$ to $150^{\circ}C$	500	V	
V <sub>GS</sub>		±20	V	
I <sub>D25</sub> I <sub>D90</sub>	$\begin{array}{l} T_{\mathrm{C}}=25^{\circ}C\\ T_{\mathrm{C}}=90^{\circ}C \end{array}$	21 15	A A	

Symbol	Conditions	$(T_{vJ} = 25^{\circ}C, \text{ unless otherwise specified})$			
		min.	typ.	max.	
R <sub>DSon</sub>	$V_{gs} = 10 \text{ V}; I_{D} = I_{D90}$			220	$m\Omega$
V <sub>GSth</sub>	$V_{_{DS}} = 20 \text{ V}; I_{_{D}} = 0.25 \text{ mA}$	2.5		4.5	V
I <sub>DSS</sub>	$V_{_{DS}} = V_{_{DSS}}; V_{_{GS}} = 0 \text{ V};  \text{T}_{_{VJ}} = \\        $		250	250	μΑ μΑ
I <sub>GSS</sub>	$V_{_{GS}} = \pm 20 \text{ V}; V_{_{DS}} = 0 \text{ V}$			200	nA
Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub>	$\left. \right\} V_{GS} = 10 V; V_{DS} = 0.5 \bullet V_{DSS};$	$I_{D} = 14 \text{ A}$	95 20 42		nC nC nC
$\begin{array}{c} \\ t_{d(on)} \\ t_{r} \\ t_{d(off)} \\ t_{f} \end{array}$	$\begin{cases} V_{GS} = 10 \text{ V};  V_{DS} = 0.5 \bullet V_{DSS} \\ I_D = 14  A;  R_G = 2  \Omega \end{cases}$		20 20 50 15		ns ns ns ns
R <sub>thJC</sub> R <sub>thJH</sub>	with heat transfer paste		0.93		K/W K/W



Free Wheeling Diode (data for series connection)	
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Symbol	Conditions	Maximum Ra	Maximum Ratings		
V <sub>RRM</sub>	$T_{vJ} = 25^{\circ}C$ to $150^{\circ}C$	600	V		
I <sub>F25</sub> I <sub>F90</sub>	$T_c = 25^{\circ}C$ $T_c = 90^{\circ}C$	60 40	A A		

Symbol	Conditions	Ch	Characteristic Values	
		min.	typ.	max.
V <sub>F</sub>	$I_{F} = 15 \text{ A}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2.5 1.9	2.8 V V
I <sub>R</sub>	$V_{_{R}} = V_{_{RRM}}; T_{_{VJ}} = 25^{\circ}C$ $T_{_{VJ}} = 125^{\circ}C$		0.13	0.13 mA mA
l <sub>RM</sub> t <sub>rr</sub>	$\left. \begin{array}{l} I_{_{\rm F}} = 30 \text{ A}; \ di_{_{\rm F}}/dt = -500 \text{ A}/\mu s; \ T_{_{\rm VJ}} = 125^{\circ} \text{C} \\ V_{_{\rm R}} = 300 \text{ V} \end{array} \right.$		9 40	A ns
R <sub>thJC</sub> R <sub>thJH</sub>	with heat transfer paste		1.3	0.65 K/W K/W

Component				
Symbol	Conditions	Maximum Ratings		
T <sub>vj</sub> T <sub>stg</sub>		-55+150 -55+125	°C ℃	
V <sub>ISOL</sub>	I <sub>ISOL</sub> ≤ 1 mA; 50/60 Hz	2500	V~	
F <sub>c</sub>	mounting force with clip	20120	Ν	

Symbol	Conditions	Ch min.	Characteristic Values min.   typ.   max.	
C <sub>p</sub>	coupling capacity between shorted pins and mounting tab in the case		40	pF
d <sub>s</sub> ,d <sub>A</sub> d <sub>s</sub> ,d <sub>A</sub>	pin - pin pin - backside metal	1.7 5.5		mm mm
Weight			9	g

